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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild questions@onsemi.com.

EMIC NDUCT R



Pin Definitions		
Number	Name	Function Description
1	ANODE	Anode
3	CATHODE	Cathode
4	GND	Output Ground
5	V _O	Output Voltage
6	V _{CC}	Output Supply Voltage

Safety and Insulation Ratings for Mini-Flat Package (SO5 Pin)

As per IEC60747-5-2 (Pending Certification). This optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				
	For rated main voltage < 150Vrms		I-IV		
	For rated main voltage < 300Vrms		1-111		
	Climatic Classification		40/85/21		
	Pollution Degree (DIN VDE 0110/1.89)		2		
CTI	Comparative Tracking Index	175			
V _{PR}	Input to Output Test Voltage, Method b, VIORM x 1.875 = V_{PR} , 100% Production Test with $t_m = 1$ sec, Partial Discharge < 5 pC	1060			
V _{PR}	Input to Output Test Voltage, Method a, VIORM x 1.5 = V_{PR} , Type and Sample Test with $t_m = 60$ sec, Partial Discharge < 5 pC	848			
VIORM	Max Working Insulation Voltage	565			V _{peak}
V _{IOTM}	Highest Allowable Over Voltage	4000			V _{peak}
	External Creepage	5.0			mm
	External Clearance	5.0			mm
	Insulation thickness	0.5			mm
T _{Case}	Safety Limit Values, Maximum Values allowed in the event of a failure, Case Temperature	150			°C
R_{IO}	Insulation Resistance at T_S , $V_{IO} = 500V$	10 ⁹			Ω

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
T _{STG}	Storage Temperature	-40 to +125	°C
T _{OPR}	Operating Temperature	-40 to +85	٥C
TJ	Junction Temperature	-40 to +125	°C
T _{SOL}	Lead Solder Temperature (Refer to Reflow Temperature Profile)	260 for 10sec	°C
١ _F	Forward Current	50	mA
V _R	Reverse Voltage	5.0	V
V _{CC}	Supply Voltage	0 to 7.0	V
Vo	Output Voltage	-0.5 to V _{CC} +0.5	V
Ι _Ο	Average Output Current	50	mA
PDI	Input Power Dissipation ⁽¹⁾⁽²⁾	100	mW
PDO	Output Power Dissipation ⁽¹⁾⁽²⁾	85	mW

Recommended Operating Conditions

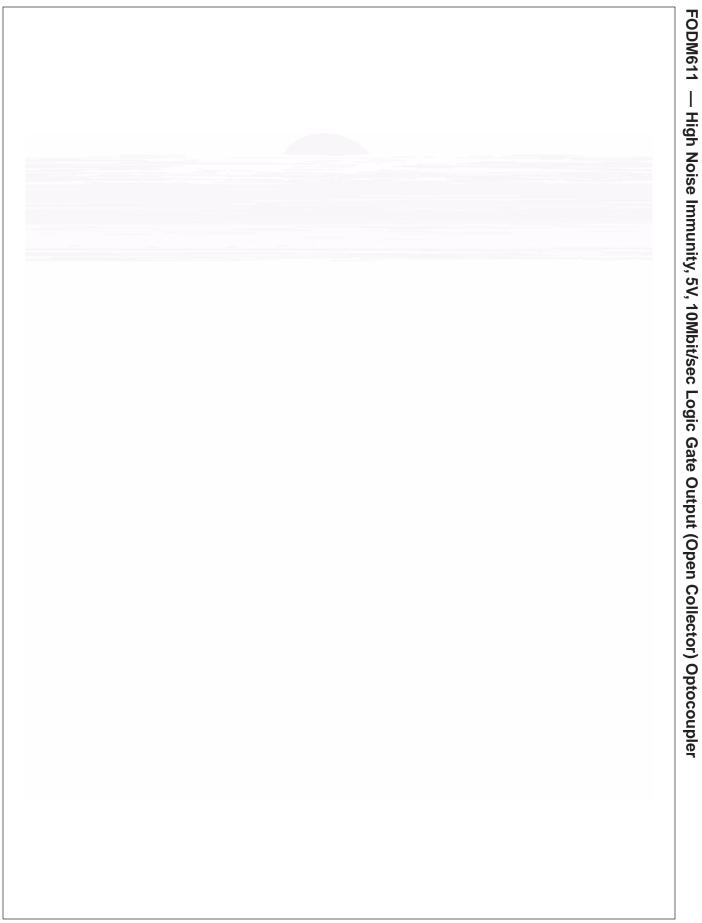
The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

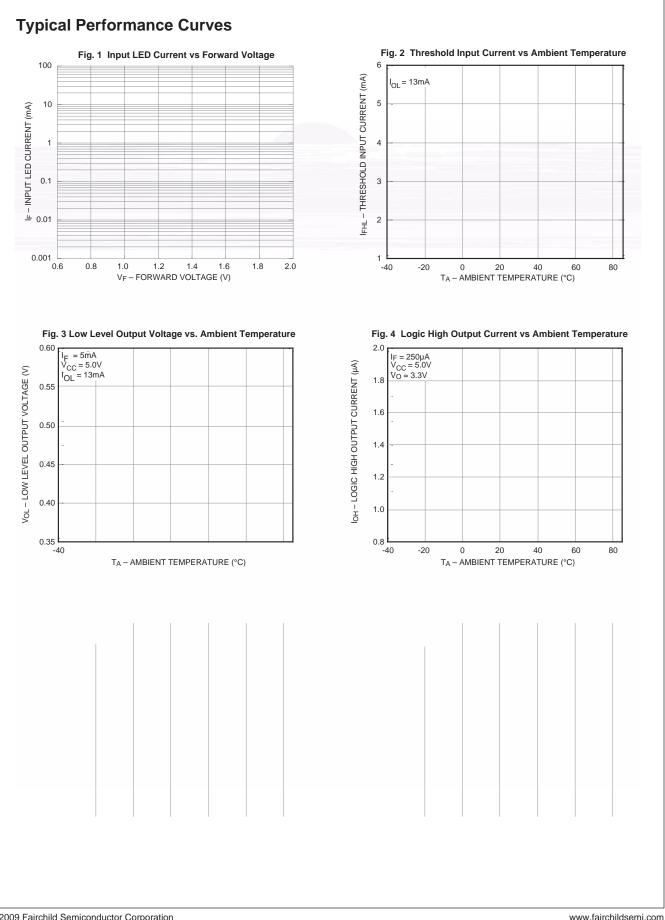
Symbol	Parameter	Min.	Max.	Unit
T _A	Ambient Operating Temperature	-40	+85	°C
V _{CC}	Supply Voltages ⁽³⁾	4.5	5.5	V
V _{FL}				

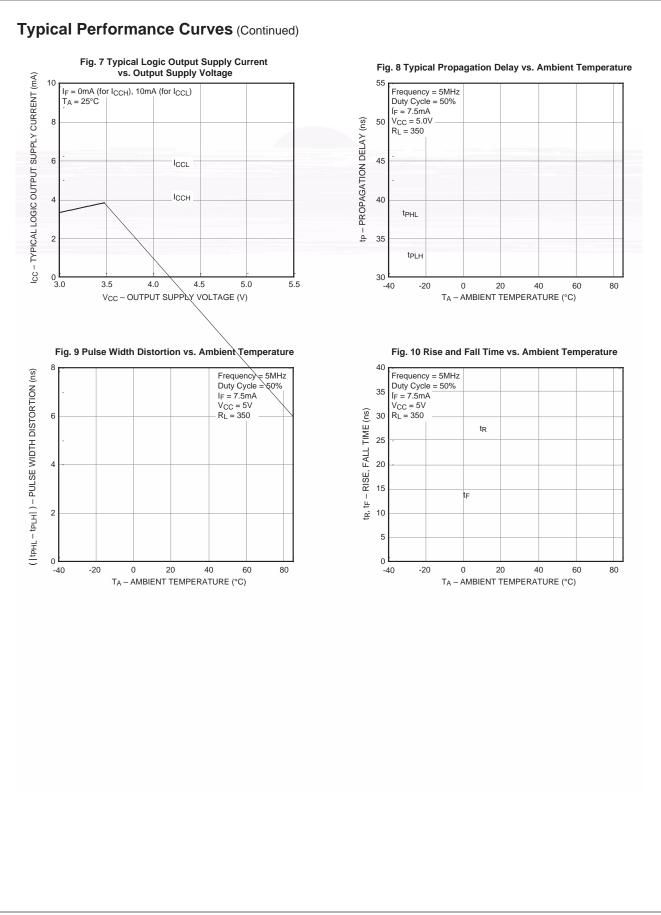
Isolation Characteristics (T_A=25°C)

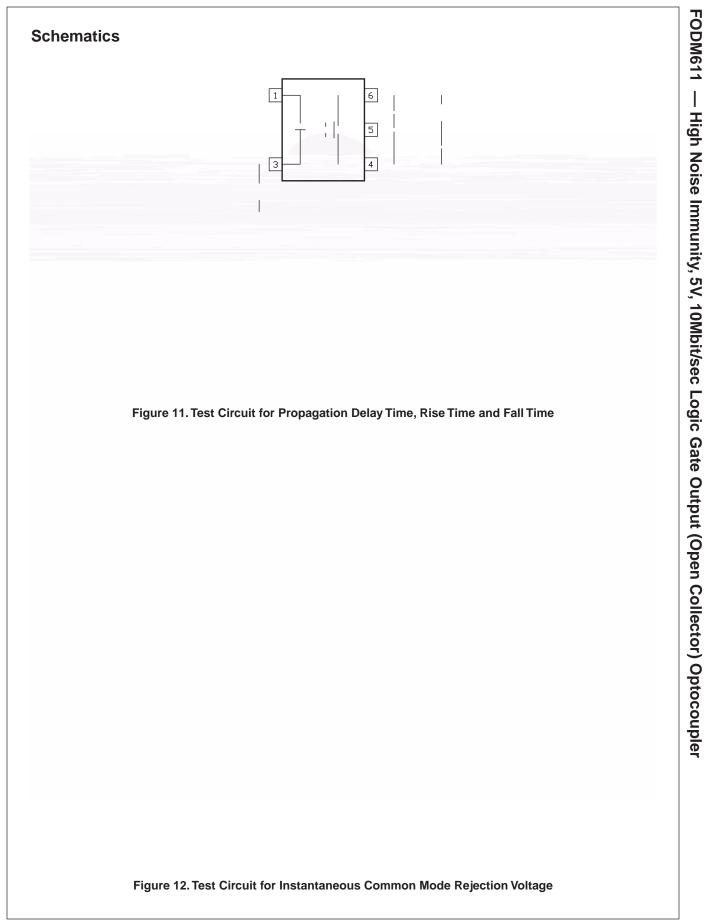
Notes:

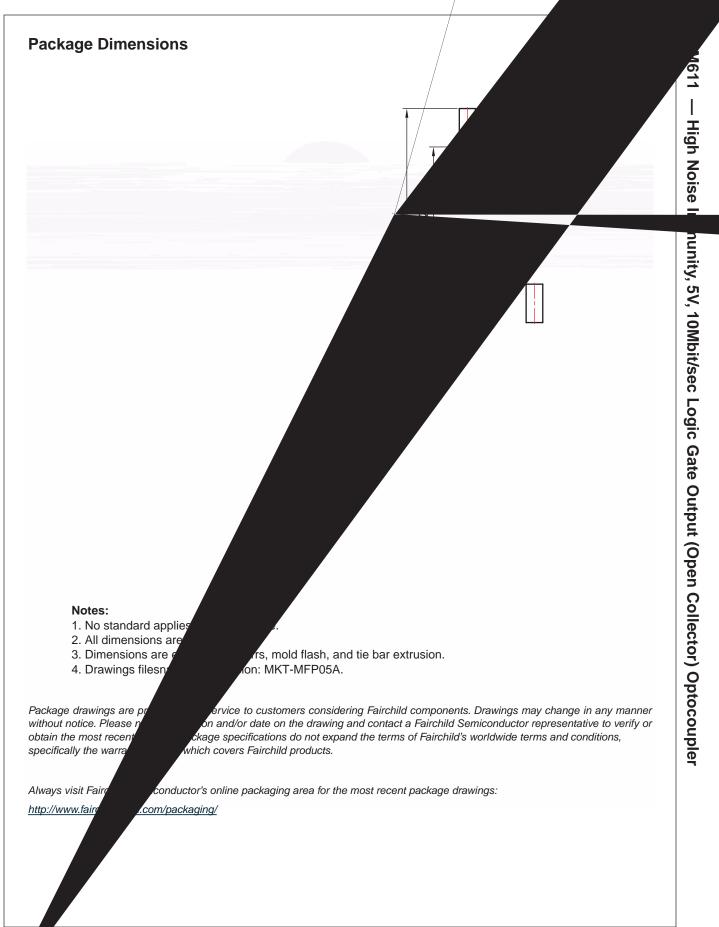
- 1. No derate required to 85°C.
- 2. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.
- 3. $0.1 \mu F$ bypass capacitor must be connected between pins 4 and 6.
- 4. Device is considered a two terminal device: Pins 1 and 3 are shorted, and Pins 4, 5, and 6 are shorted together.
- 5. 3,750 VAC_{RMS} for 1 minute duration is equivalent to 4,500 VAC_{RMS} for 1 second duration.











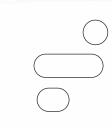
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Ordering Information

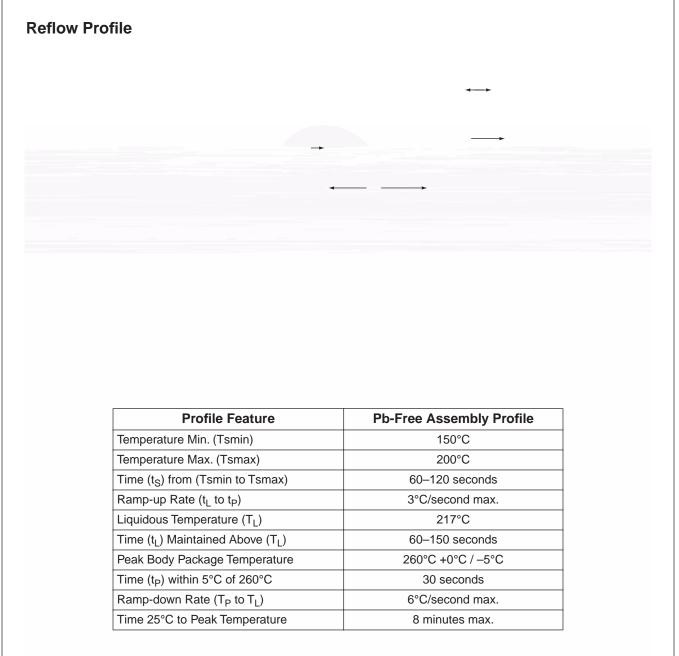
Option	Order Entry Identifier (Example)	Description
No Suffix	FODM611	Mini-Flat 5-pin, shipped in tubes (100 units per tube)
R2	FODM611R2	Mini-Flat 5-pin, tape and reel (2,500 units per reel)

All packages are lead free per JEDEC: J-STD-020B standard.

Marking Information



VV1		
Description	Symbol	Dimensions (mm)
Tape Width	W	12.00 +0.30/-0.10
Tape Thickness	t	
Sprocket Hole Pitch	P ₀	
Sprocket Hole Diameter	D ₀	
Sprocket Hole Location	E	
Pocket Location	F	7.30 xµ8753644480337130578 Q35 80
	P ₂	
	Р	
Pocket Pitch	+	
Pocket Pitch Pocket Dimension	A ₀	
	A ₀ B ₀	7.30 pp87584448059400055510-17
		7.30 20875584448059400055320-17
	B ₀	7.30 1208753844480539400055356-17
Pocket Dimension	B ₀ K ₀	7.30 pp87588444805940005531p-17
Pocket Dimension Pocket Hole Diameter	B ₀ K ₀ D ₁	7.30 ชุว87 5 8444805540005535p-17
Pocket Dimension Pocket Hole Diameter Cover Tape Width	B0 K0 D1 W1	7.30 ชา87588444805940005535p-17
Pocket Dimension Pocket Hole Diameter Cover Tape Width Cover Tape Thickness	B0 K0 D1 W1	7.30 ซมุ8753844480534,0005533b-17



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